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**Electronic Structure and Magnetism of Ir based Oxides**<sup>1</sup> INDRA DASGUPTA<sup>2</sup>, Department of Solid State Physics, SWARUP PANDA<sup>3</sup>, None — We have investigated in details the electronic structure of several Ir based oxides where in addition to crystal field and Coulomb repulsion, the spin-orbit coupling (SOC) plays an important role. We shall first consider two Ir based oxides with 4+ ( $d^5$ ) charge state of Ir, namely the insulating double perovskite  $\text{Sr}_2\text{CeIrO}_6$  and the metallic rutile  $\text{IrO}_2$ , and examine the validity of the novel spin-orbital entangled  $J_{eff}=1/2$  states for the description of their electronic structure. In particular, explore in details whether the  $J_{eff}=1/2$  state survives for the itinerant metallic  $\text{IrO}_2$ . Finally we shall also present our electronic structure calculations on 6H perovskite type iridates where different charge state of Ir (5+, 4.5+, and 4+) may be realized. We show in addition to SOC, the strong intra-dimer hopping play a crucial role for the magnetic ground state and the insulating property of these systems. We shall compare our results with available experiments.

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